

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

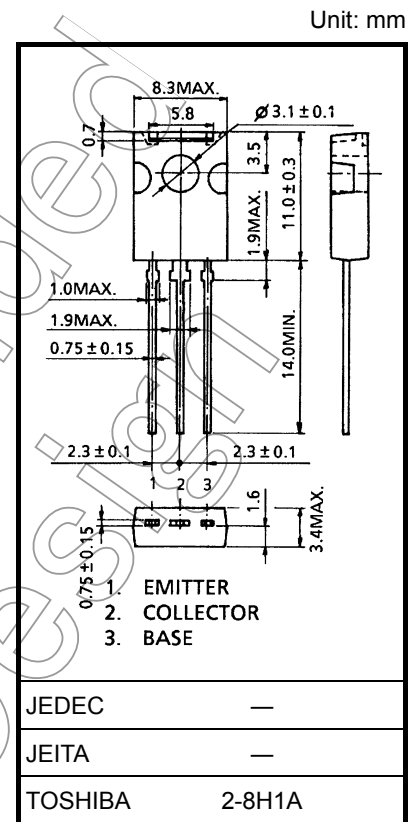
2SC3419

Medium-Power Amplifier Applications.

- Low saturation voltage: $V_{CE(sat)} = 0.25\text{ V (typ.)}$
($I_C = 500\text{ mA}$, $I_B = 50\text{ mA}$)
- High collector power dissipation: $P_C = 1.2\text{ W (Ta = 25°C)}$
- Complementary to 2SA1356

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	40	V
Collector-emitter voltage		V_{CEO}	40	V
Emitter-base voltage		V_{EBO}	5	V
Collector current		I_C	800	mA
Base current		I_B	80	mA
Collector power dissipation	Ta = 25°C	PC	1.2	W
	Tc = 25°C		5	
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-55 to 150	°C



Weight: 0.82 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

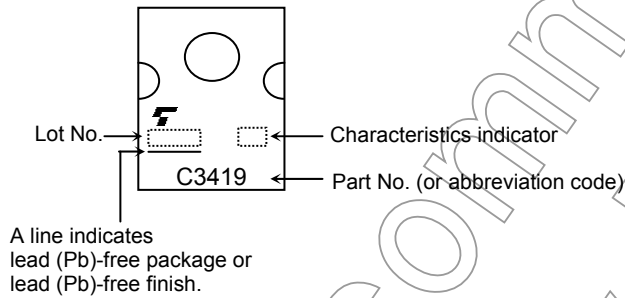
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Electrical Characteristics (Tc = 25°C)

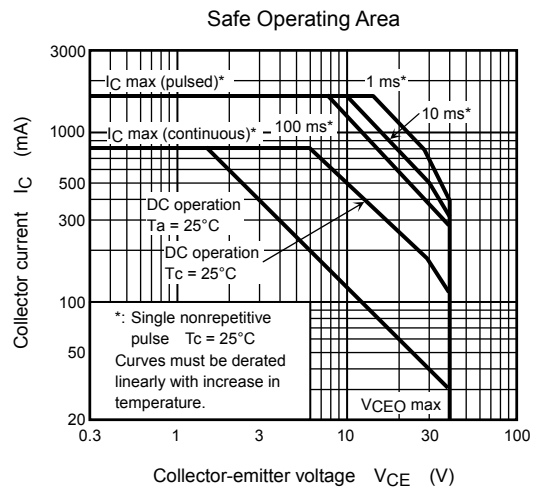
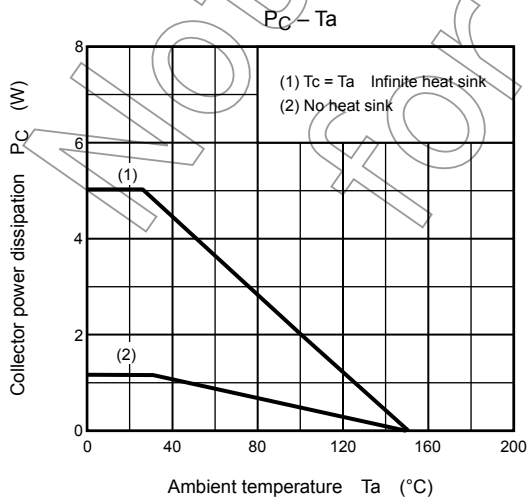
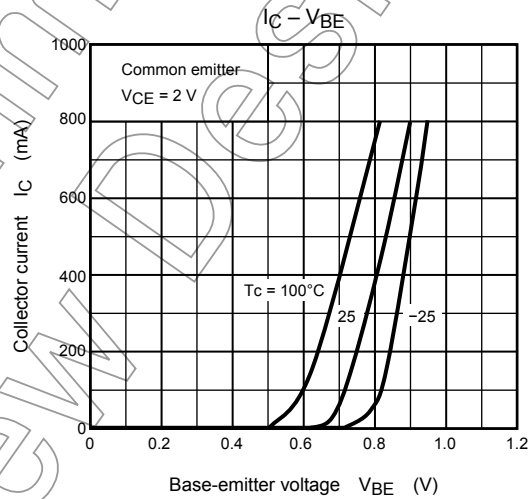
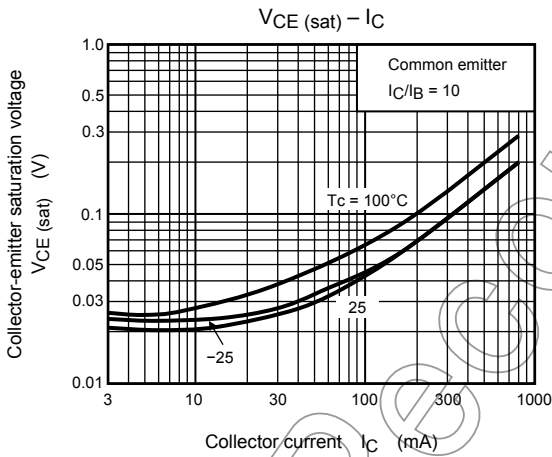
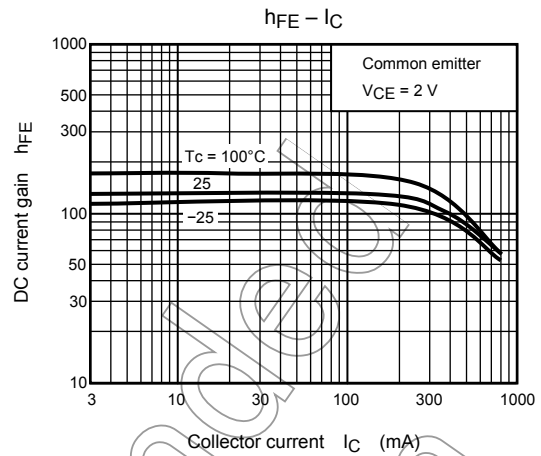
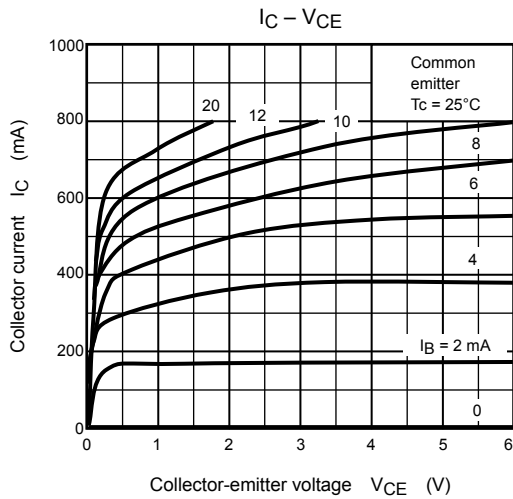
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 40\text{ V}, I_E = 0$	—	—	1.0	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 5\text{ V}, I_C = 0$	—	—	1.0	μA
Collector-emitter breakdown voltage	V_{CEO}	$I_C = 10\text{ mA}, I_B = 0$	40	—	—	V
DC current gain	$h_{FE(1)}$ (Note)	$V_{CE} = 2\text{ V}, I_C = 50\text{ mA}$	70	—	240	
	$h_{FE(2)}$	$V_{CE} = 2\text{ V}, I_C = 0.8\text{ A}$	13	60	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 500\text{ mA}, I_B = 50\text{ mA}$	—	0.25	0.8	V
Base-emitter voltage	V_{BE}	$V_{CE} = 2\text{ V}, I_C = 500\text{ mA}$	—	0.90	1.1	V
Transition frequency	f_T	$V_{CE} = 2\text{ V}, I_C = 0.5\text{ A}$	50	100	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	10	—	pF

Note: $h_{FE(1)}$ classification O: 70 to 140, Y: 120 to 240

Marking



Not Recommended for New Design



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